

LP5900 Ultra Low Noise, 150 mA Linear Regulator for RF/Analog Circuits Requires No Bypass Capacitor

General Description

The LP5900 is a linear regulator capable of supplying 150 mA output current. Designed to meet the requirements of RF/ Analog circuits, the LP5900 device provides low noise, high PSRR, low quiescent current, and low line transient response figures. Using new innovative design techniques the LP5900 offers class-leading device noise performance without a noise bypass capacitor.

The device is designed to work with 0.47 μF input and output ceramic capacitors. (No Bypass Capacitor is required)

The device is available in micro SMD package and LLP package. For all other package options contact your local NSC sales office.

This device is available with 1.5V,1.575V, 1.8V, 1.9V, 2.0V, 2.1V, 2.2V, 2.5V, 2.6V, 2.7V, 2.75V 2.8V, 2.85V 3.0V, and 3.3V outputs. Please contact your local sales office for any other voltage options.

Features

- Stable with 0.47 µF Ceramic Input and Output Capacitors
- No Noise Bypass Capacitor Required
- Logic Controlled Enable
- Thermal-overload and short-circuit protection
- –40°C to +125°C junction temperature range for operation

Typical Application Circuit

Key Specifications

Input voltage range	2.5V to 5.5V
 Output voltage range 	1.5V to 3.3V
 Output current 	150 mA
 Low output voltage noise 	6.5 μV _{BMS}
■ PSRR	75 dB at 1 kHz
 Output voltage tolerance 	± 2%
 Virtually zero I_Q (disabled) 	<1 µA
 Very low I_Q (enabled) 	25 µA
 Start-up time 	150 µs
Low dropout	80 mV typ.

Package

4-Bump micro SMD	1.057 mm x 1.083 mm
(lead free)	
6 Pin LLP (SC-70 footprint)	2.2 mm x 2.5 mm

Applications

- Cellular phones
- PDA handsets
- Wireless LAN devices

April 22, 2008

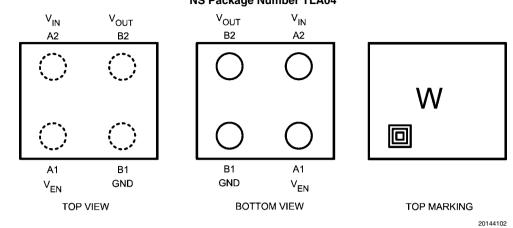
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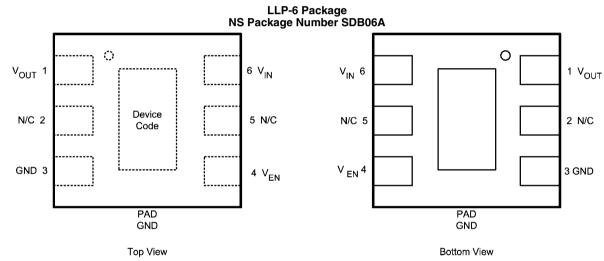
$INPUT \bigoplus_{i} 0.47 \ \mu F \bigoplus_{i} V_{OUT} \bigoplus_{i} 0.47 \ \mu F \bigoplus$

Connection Diagrams

4-Bump Thin micro SMD Package, Large Bump NS Package Number TLA04



The actual physical placement of the package marking will vary from part to part.



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Pin Descriptions

Pin No.		Symbol	Name and Function
micro SMD	LLP		
A1	4	V _{EN}	Enable input; disables the regulator when \leq 0.4V. Enables the regulator when \geq 1.2V. An internal 1 M Ω pulldown resistor connects this input to ground.
B1	3	GND	Common ground
B2	1	V _{OUT}	Output voltage. A 0.47 μ F Low ESR capacitor should be connected to this Pin. Connect this output to the load circuit.
A2	6	V _{IN}	Input voltage supply. A 0.47 μF capacitor should be connected at this input.
	Pad	GND	Common Ground. Connect to Pin 3.

LP5900

Ordering Information

micro SMD Package (Lead Free)

Output Voltage (V)	Suppl	Package Marking	
	250 Units Tape and Reel	3k Units Tape and Reel	
1.5	LP5900TL-1.5/NOPB	LP5900TLX-1.5/NOPB	
1.575	LP5900TL-1.575/NOPB	LP5900TLX-1.575/NOPB	
1.8	LP5900TL-1.8/NOPB	LP5900TLX-1.8/NOPB	
1.9	LP5900TL-1.9/NOPB	LP5900TLX-1.9/NOPB	
2.0	LP5900TL-2.0/NOPB	LP5900TLX-2.0/NOPB	
2.1	LP5900TL-2.1/NOPB	LP5900TLX-2.1/NOPB	
2.2	LP5900TL-2.2/NOPB	LP5900TLX-2.2/NOPB	
2.3**	LP5900TL-2.3/NOPB	LP5900TLX-2.3/NOPB	
2.5	LP5900TL-2.5/NOPB	LP5900TLX-2.5/NOPB	
2.6	LP5900TL-2.6/NOPB	LP5900TLX-2.6/NOPB	
2.7	LP5900TL-2.7/NOPB	LP5900TLX-2.7/NOPB	
2.75	LP5900TL-2.75/NOPB	LP5900TLX-2.75/NOPB	
2.8	LP5900TL-2.8/NOPB	LP5900TLX-2.8/NOPB	
2.85	LP5900TL-2.85/NOPB	LP5900TLX-2.85/NOPB	
3.0	LP5900TL-3.0/NOPB	LP5900TLX-3.0/NOPB	
3.3	LP5900TL-3.3/NOPB	LP5900TLX-3.3/NOPB	

** For availability contact National Semiconductor local sales office

For LLP-6 Package

Output Voltage (V)	Supp	Package Marking	
	250 Units Tape and Reel	3k Units Tape and Reel	
1.5	LP5900SD-1.5/NOPB	LP5900SDX-1.5/NOPB	L15
1.8	LP5900SD-1.8/NOPB	LP5900SDX-1.8/NOPB	L17
2.0	LP5900SD-2.0/NOPB	LP5900SDX-2.0/NOPB	L18
2.2	LP5900SD-2.2/NOPB	LP5900SDX-2.2/NOPB	L19
2.5	LP5900SD-2.5/NOPB	LP5900SDX-2.5/NOPB	L13
2.7	LP5900SD-2.7/NOPB	LP5900SDX-2.7/NOPB	L14
2.8	LP5900SD-2.8/NOPB	LP5900SDX-2.8/NOPB	L12
3.0	LP5900SD-3.0/NOPB	LP5900SDX-3.0/NOPB	L20
3.3	LP5900SD-3.3/NOPB	LP5900SDX-3.3/NOPB	L16

Absolute Maximum Ratings (Notes 1, 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

V _{IN} Pin: Input Voltage	-0.3 to 6.0V
V _{OUT} Pin: Output Voltag	ge -0.3 to (V _{IN} + 0.3V) to 6.0V
	(max)
V _{EN} Pin: Enable Input V	Voltage -0.3 to (V _{IN} + 0.3V) to 6.0V
	(max)
Continuous Power Diss	ipation
(Note 3)	Internally Limited
Junction Temperature (T _{JMAX}) 150°C
Storage Temperature F	ange -65 to 150°C
Maximum Lead Tempe	rature
(Soldering, 10 sec.)	260°C
ESD Rating (Note 4)	

Human Body Model Machine Model

2 kV

200V

Operating Ratings (Note 1), (Note 2)

V _{IN} : Input Voltage Range	2.5V to 5.5V
V _{EN} : Enable Voltage Range	0 to (V _{IN} + 0.3V) to 5.5V (max)
Recommended Load Current (Note 5)	0 to 150 mA
Junction Temperature Range (T_J)	-40°C to +125°C
Ambient Temperature Range (T _A) (Note 5)	-40°C to +85°C

Thermal Properties

Junction to Ambient Thermal Resistance	θ _{JA} (Note 6)
JEDEC Board (microSMD)	
(Note 16)	88°C/W
4L Cellphone Board (microSMD)	157.4°C/W
JEDEC Board (LLP-6)(Note 16)	77.3°C/W

Electrical Characteristics

Limits in standard typeface are for $T_A = 25^{\circ}$ C. Limits in **boldface** type apply over the full operating junction temperature range (-40°C $\leq T_J \leq +125^{\circ}$ C). Unless otherwise noted, specifications apply to the LP5900 Typical Application Circuit (pg. 1) with: $V_{IN} = V_{OUT (NOM)} + 1.0V$, $V_{EN} = 1.2V$, $C_{IN} = 0.47 \ \mu$ F, $I_{OUT} = 1.0 \ m$ A. (Note 2), (Note 7)

Symbol	Parameter	Conditions	Min	Тур	Max	Units	
V _{IN}	Input Voltage		2.5		5.5	V	
ΔV _{OUT}	Output Voltage Tolerance	$V_{IN} = (V_{OUT(NOM)} + 1.0V)$ to 5.5V, $I_{OUT} = 1$ mA to 150mA	-2		2	%	
	Line Regulation	$V_{IN} = (V_{OUT(NOM)} + 1.0V)$ to 5.5V, $I_{OUT} = 1$ mA		0.05		%/V	
	Load Regulation	I _{OUT} = 1 mA to 150 mA		0.001		%/mA	
I _{LOAD}	Load Current	(Note 9)	0			mA	
	Maximum Output Current		150				
Ι _Q	Quiescent Current (Note 11)	$V_{EN} = 1.2V, I_{OUT} = 0 \text{ mA}$		25	50		
		V _{EN} = 1.2V, I _{OUT} = 150 mA		160	230	μΑ	
		V _{EN} = 0.3V (Disabled)		0.003	1.0]	
I _G	Ground Current (Note 13)	$I_{OUT} = 0 \text{ mA} (V_{OUT} = 2.5 \text{V})$		30		μA	
V _{DO}	Dropout Voltage(Note 10)	I _{OUT} = 150 mA		80	150	mV	
I _{SC}	Short Circuit Current Limit	(Note 12)		300		mA	
PSRR	Power Supply Rejection Ratio	f = 100 Hz, I _{OUT} = 150 mA		85			
	(Note 15)	f = 1 kHz, I _{OUT} = 150 mA		75]	
		f = 10 kHz, I _{OUT} = 150 mA		65		dB	
		f = 50 kHz, I _{OUT} = 150 mA		52		1	
		f = 100 kHz, I _{OUT} = 150 mA		40			
e _n	Output Noise Voltage	BW = 10 Hz to 100 kHz, I _{OUT} = 0 mA		7		μV _{RMS}	
	(Note 15)	$V_{IN} = 4.2V$ $I_{OUT} = 1 \text{ mA}$		10			
		I _{OUT} = 150 mA		6.5		1	
T _{SHUTDOWN}	Thermal Shutdown	Temperature		160		°C	
		Hysteresis		20] *	

Symbol	Parameter	Conditions	Min	Тур	Max	Units
Login Input	Thresholds					
V _{IL}	Low Input Threshold (V _{EN})	V _{IN} = 2.5V to 5.5V			0.4	V
V _{IH}	High Input Threshold (V _{EN})	V _{IN} = 2.5V to 5.5V	1.2			V
I _{EN}	Input Current at V _{EN} Pin	$V_{EN} = 5.5V$ and $V_{IN} = 5.5V$		5.5		
	(Note 14)	$V_{EN} = 0.0V$ and $V_{IN} = 5.5V$		0.001		μA
Transient C	haracteristics					
ΔV _{OUT} Line Transient (Note 15)		$ V_{\text{IN}} = (V_{\text{OUT(NOM}}) + 1.0V) \text{ to } (V_{\text{OUT(NOM}}) + 1.6V) \text{ in 30 } \mu\text{s}, I_{\text{OUT}} = 1 \text{ mA} $	-2			mV
		$V_{IN} = (V_{OUT(NOM)} + 1.6V) \text{ to } (V_{OUT(NOM)} + 1.0V) \text{ in 30 } \mu\text{s}, I_{OUT} = 1 \text{ mA}$			2	
	Load Transient	I _{OUT} = 1 mA to 150 mA in 10 μs	-110			
	(Note 15)	I _{OUT} = 150 mA to 1 mA in 10 μs			50	mV
	Overshoot on Startup (Note 15)				20	mV
	Turn on Time	To 95% of V _{OUT(NOM)}		150	300	μs

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the component may occur. Operating Ratings are conditions under which operation of the device is guaranteed. Operating Ratings do not imply guaranteed performance limits. For guaranteed performance limits and associated test conditions, see the Electrical Characteristics tables.

Note 2: All voltages are with respect to the potential at the GND pin.

Note 3: Internal thermal shutdown circuitry protects the device from permanent damage.

Note 4: The Human body model is a 100 pF capacitor discharged through a 1.5 kΩ resistor into each pin. The machine model is a 200 pF capacitor discharged directly into each pin. MIL-STD-883 3015.7

Note 5: In applications where high power dissipation and/or poor package thermal resistance is present, the maximum ambient temperature may have to be derated. Maximum ambient temperature (T_{A-MAX}) is dependent on the maximum operating junction temperature ($T_{J-MAX-OP} = 125^{\circ}$ C), the maximum power dissipation of the device in the application (P_{D-MAX}), and the junction-to ambient thermal resistance of the part/package in the application (θ_{JA}), as given by the following equation: $T_{A-MAX} = T_{J-MAX-OP} - (\theta_{JA} \times P_{D-MAX})$. See applications section.

Note 6: Junction-to-ambient thermal resistance is highly application and board-layout dependent. In applications where high maximum power dissipation exists, special care must be paid to thermal dissipation issues in board design.

Note 7: Min and Max limits are guaranteed by design, test, or statistical analysis. Typical numbers are not guaranteed, but do represent the most likely norm.

Note 8: CIN, COUT: Low-ESR Surface-Mount Ceramic Capacitors (MLCCs) used in setting electrical characteristics.

Note 9: The device maintains a stable, regulated output voltage without a load current.

Note 10: Dropout voltage is the voltage difference between the input and the output at which the output voltage drops to 100 mV below its nominal value. This parameter only applies to output voltages above 2.5V.

Note 11: Quiescent current is defined here as the difference in current between the input voltage source and the load at V_{OUT}.

Note 12: Short Circuit Current is measured with V_{OUT} pulled to 0v and V_{IN} worst case = 6.0V.

Note 13: Ground current is defined here as the total current flowing to ground as a result of all input voltages applied to the device.

Note 14: There is a 1 M Ω resistor between V_{EN} and ground on the device.

Note 15: This specification is guaranteed by design.

Note 16: Detailed description of the board can be found in JESD51-7

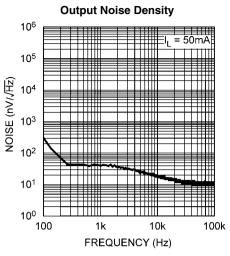
Output & Input Capacitor, Recommended Specifications

Symbol	Parameter	Conditions	Min	Nom	Мах	Units
C _{IN}	Input Capacitance	Capacitance for stability	0.33	0.47		μF
C _{OUT}	Output Capacitance		0.33	0.47	10	
ESR	Output/Input Capacitance		5		500	mΩ

Note: The minimum capacitance should be greater than $0.33 \,\mu$ F over the full range of operating conditions. The capacitor tolerance should be 30% or better over the full temperature range. The full range of operating conditions for the capacitor in the application should be considered during device selection to ensure this minimum capacitance specification is met. X7R capacitors are recommended however capacitor types X5R, Y5V and Z5U may be used with consideration of the application and conditions.

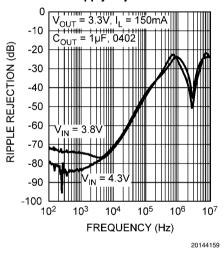
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Typical Performance Characteristics. Unless otherwise specified, $C_{IN} = C_{OUT} = 0.47 \mu$ F, $V_{IN} = V_{OUT}$ (NOM) + 1.0V, $V_{EN} = 1.2$ V, $I_{OUT} = 1$ mA, $T_A = 25^{\circ}$ C.

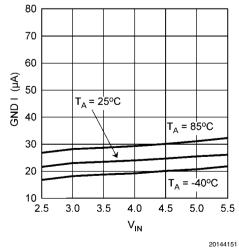


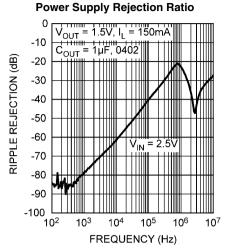
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Power Supply Rejection Ratio



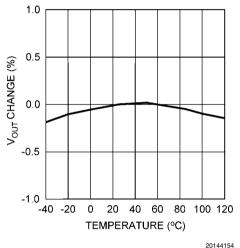


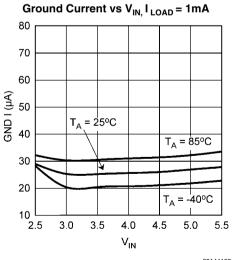




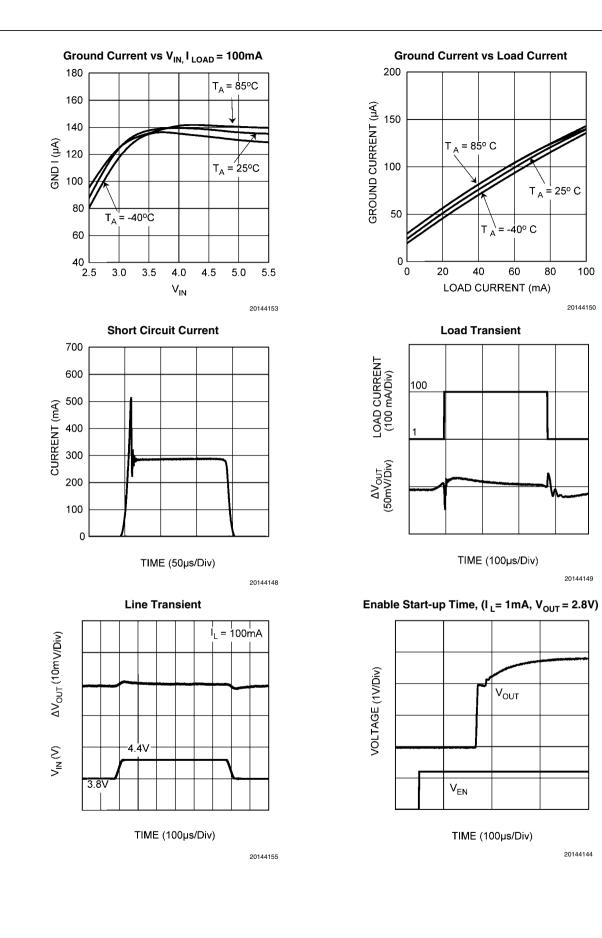
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Output Voltage Change vs Temperature

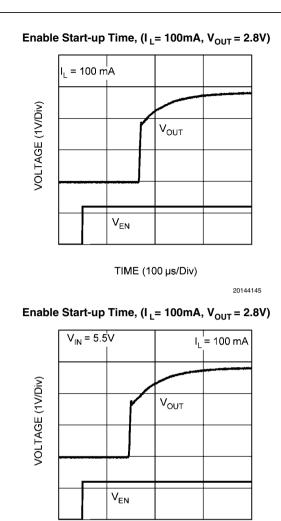




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LP5900





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Application Hints

POWER DISSIPATION AND DEVICE OPERATION

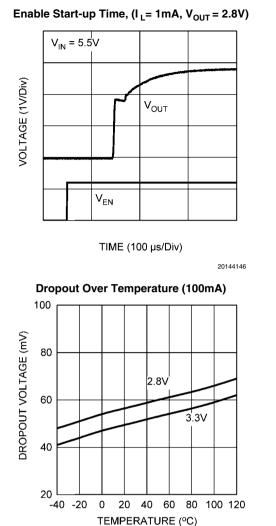
The permissible power dissipation for any package is a measure of the capability of the device to pass heat from the power source, the junctions of the IC, to the ultimate heat sink, the ambient environment. Thus the power dissipation is dependent on the ambient temperature and the thermal resistance across the various interfaces between the die and ambient air. As stated in (Note 5) of the electrical characteristics, the allowable power dissipation for the device in a given package can be calculated using the equation:

$$P_{D} = \frac{(T_{JMAX} - T_{A})}{\theta_{JA}}$$

The actual power dissipation across the device can be represented by the following equation:

$$P_{D} = (V_{IN} - V_{OUT}) \times I_{OUT}$$

This establishes the relationship between the power dissipation allowed due to thermal consideration, the voltage drop across the device, and the continuous current capability of the



device. These two equations should be used to determine the optimum operating conditions for the device in the application.

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EXTERNAL CAPACITORS

Like any low-dropout regulator, the LP5900 requires external capacitors for regulator stability. The LP5900 is specifically designed for portable applications requiring minimum board space and smallest components. These capacitors must be correctly selected for good performance.

INPUT CAPACITOR

An input capacitor is required for stability. The input capacitor should be at least equal to or greater than the output capacitor. It is recommended that a 0.47 μ F capacitor be connected between the LP5900 input pin and ground.

This capacitor must be located a distance of not more than 1 cm from the input pin and returned to a clean analogue ground. Any good quality ceramic, tantalum, or film capacitor may be used at the input.

Important: To ensure stable operation it is essential that good PCB practices are employed to minimize ground impedance and keep input inductance low. If these conditions cannot be met, or if long leads are to be used to connect the battery or other power source to the LP5900, then it is recommended to increase the input capacitor to at least 2.2µF.

means that while it may be possible to find a tantalum capacitor with an ESR value within the stable range, it would have to be larger in capacitance (which means bigger and more costly) than a ceramic capacitor with the same ESR value. It should also be noted that the ESR of a typical tantalum will

Also, tantalum capacitors can suffer catastrophic failures due to surge current when connected to a low-impedance source of power (like a battery or a very large capacitor). If a tantalum capacitor is used at the input, it must be guaranteed by the manufacturer to have a surge current rating sufficient for the application. There are no requirements for the ESR (Equivalent Series Resistance) on the input capacitor, but tolerance and temperature coefficient must be considered when selecting the capacitor to ensure the capacitance will remain 0.47 μ F ±30% over the entire operating temperature range.

OUTPUT CAPACITOR

The LP5900 is designed specifically to work with very small ceramic output capacitors. A ceramic capacitor (dielectric types X5R or X7R) in the 0.47 μ F to 10 μ F range, and with ESR between 5 m Ω to 500 m Ω , is suitable in the LP5900 application circuit. For this device the output capacitor should be connected between the V_{OUT} pin and a good ground connection and should be mounted within 1 cm of the device.

It may also be possible to use tantalum or film capacitors at the device output, V_{OUT} , but these are not as attractive for reasons of size and cost (see the section Capacitor Characteristics).

The output capacitor must meet the requirement for the minimum value of capacitance and have an ESR value that is within the range 5 m Ω to 500 m Ω for stability.

CAPACITOR CHARACTERISTICS

The LP5900 is designed to work with ceramic capacitors on the input and output to take advantage of the benefits they offer. For capacitance values in the range of 0.47 μ F to 4.7 μ F, ceramic capacitors are the smallest, least expensive and have the lowest ESR values, thus making them best for eliminating high frequency noise. The ESR of a typical 0.47 μ F ceramic capacitor is in the range of 20 m Ω to 40 m Ω , which easily meets the ESR requirement for stability for the LP5900. The temperature performance of ceramic capacitors varies by

type and manufacturer. Most large value ceramic capacitors values by $(\geq 2.2 \ \mu\text{F})$ are manufactured with Z5U or Y5V temperature characteristics, which results in the capacitance dropping by more than 50% as the temperature goes from 25°C to 85°C.

A better choice for temperature coefficient in a ceramic capacitor is X7R. This type of capacitor is the most stable and holds the capacitance within $\pm 15\%$ over the temperature range. Tantalum capacitors are less desirable than ceramic for use as output capacitors because they are more expensive when comparing equivalent capacitance and voltage ratings in the 0.47 μ F to 4.7 μ F range.

Another important consideration is that tantalum capacitors have higher ESR values than equivalent size ceramics. This

NO-LOAD STABILITY

The LP5900 will remain stable and in regulation with no external load.

increase about 2:1 as the temperature goes from 25°C down

to -40°C, so some guard band must be allowed.

ENABLE CONTROL

The LP5900 may be switched ON or OFF by a logic input at the ENABLE pin. A high voltage at this pin will turn the device on. When the enable pin is low, the regulator output is off and the device typically consumes 3nA. However if the application does not require the shutdown feature, the V_{EN} pin can be tied to V_{IN} to keep the regulator output permanently on. In this case the supply voltage must be fully established 500µs or less to ensure correct operation of the start-up circuit. Failure to comply with this condition may cause a delayed start-up time of several seconds.

A 1M\Omega pulldown resistor ties the V_{EN} input to ground, this ensures that the device will remain off when the enable pin is left open circuit. To ensure proper operation, the signal source used to drive the V_{EN} input must be able to swing above and below the specified turn-on/off voltage thresholds listed in the Electrical Characteristics section under V_{II} and V_{IH}.

micro SMD MOUNTING

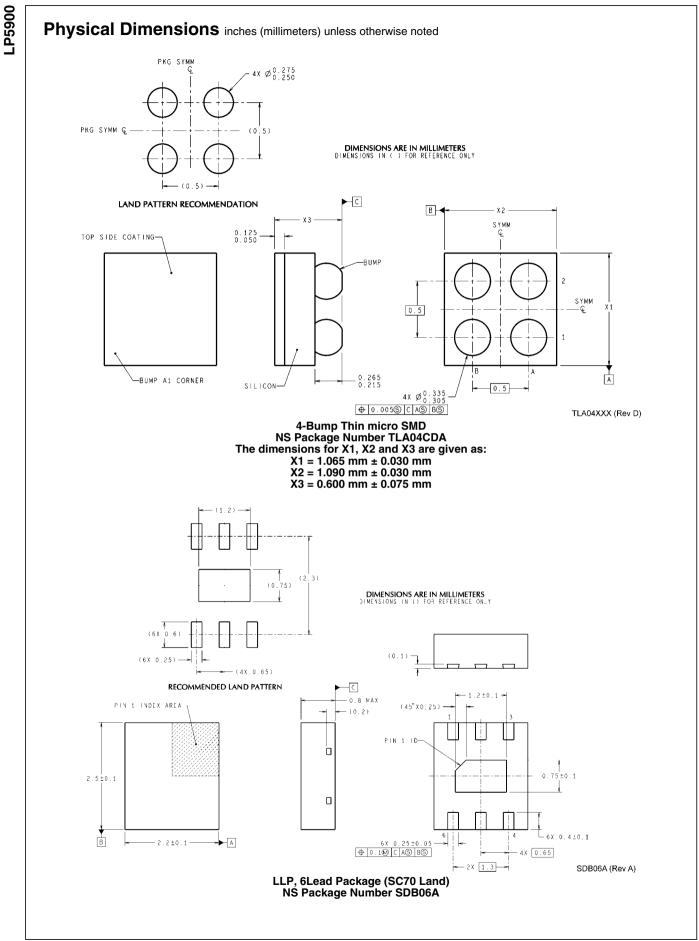
The micro SMD package requires specific mounting techniques, which are detailed in National Semiconductor Application Note AN-1112.

For best results during assembly, alignment ordinals on the PC board may be used to facilitate placement of the micro SMD device.

micro SMD LIGHT SENSITIVITY

Exposing the micro SMD device to direct light may cause incorrect operation of the device. Light sources such as halogen lamps can affect electrical performance if they are situated in proximity to the device.

Light with wavelengths in the red and infra-red part of the spectrum have the most detrimental effect thus the fluorescent lighting used inside most buildings has very little effect on performance.



Notes

Notes

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